SQUID Multiplexers for Cryogenic Detector Arrays

NIST

Kent Irwin

James Beall

Steve Deiker

Randy Doriese

Gene Hilton

Nathan Miller

Carl Reintsema

Leila Vale

Joel Ullom

Barry Zink

PTB Berlin

Joern Beyer

NASA/GSFC

Dominic Benford

James Chervenak

S. Harvey Moseley

Umesh Patel

Rick Shafer

Johannes Staguhn

Caroline Stahle

UK ATC

Damian Audley

William Duncan

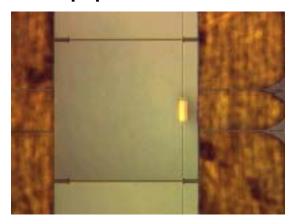
Wayne Holland

Mike MacIntosh



Some TES Bolometers fabricated at NIST

"Popup" TES bolometer



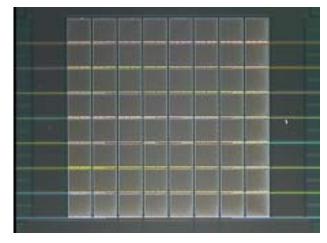
1 × 8 Popup Array



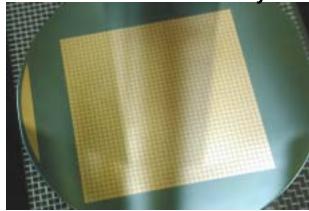
Collaboration with Harvey Moseley, NASA/GSFC



8 × 8 X-Ray Array



32 × 40 SCUBA-2 Array

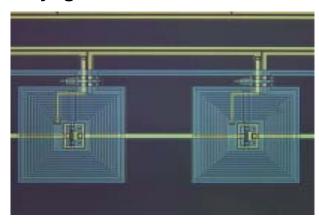


(SCUBA-2 array not yet micromachined)
Collaboration with SCUBA-2 Consortium

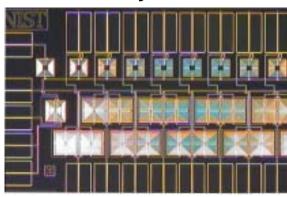
Nb SQUID Processing

- Fabricated at NIST
- Standard Nb/Al/Al₂O₃/Nb trilayer technology
- Robust and rad hard
- Works up to near the Nb transition temperature (9 K)

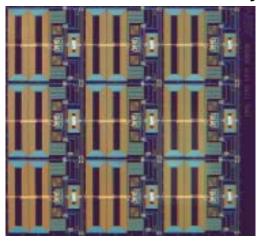
100-SQUID Series Array for the Cryogenic Dark Matter Search



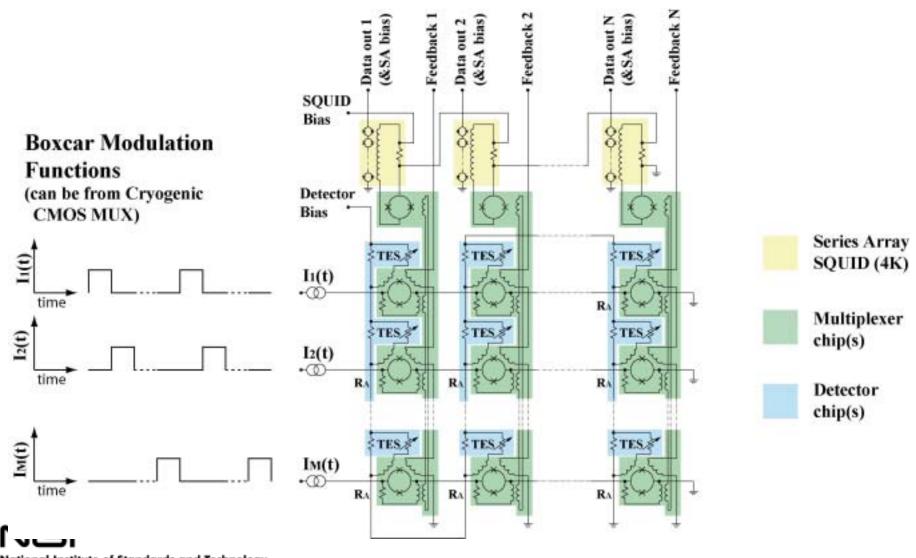
1 × 32 MUX Array for Constellation-X



3 × 3 SCUBA-2 MUX Array



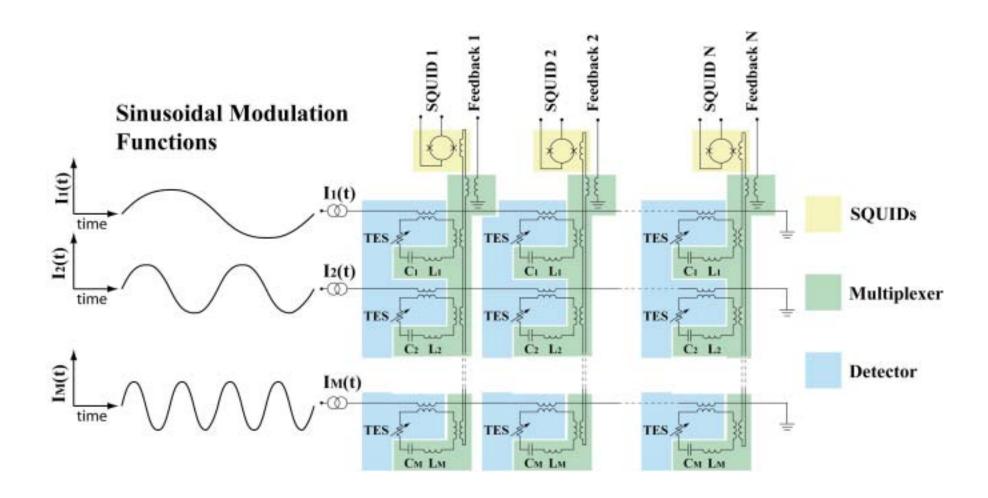
Time-Division SQUID Multiplexer



National Institute of Standards and Technology

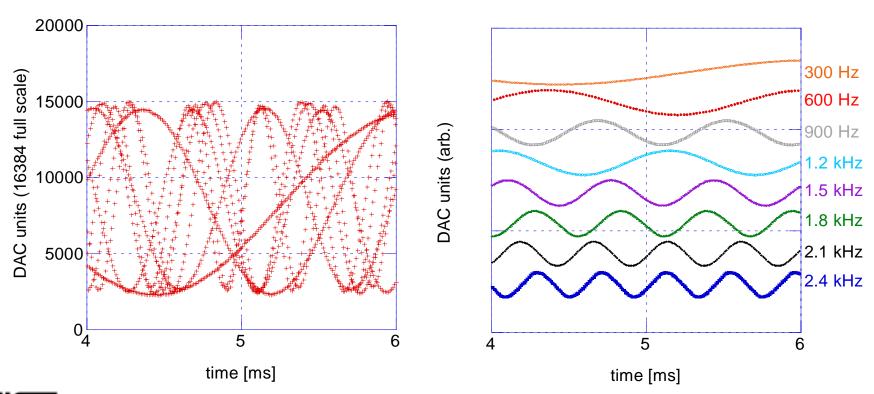
Technology Administration, U.S. Department of Commerce

Frequency-Division SQUID Multiplexer



MUX Functionality

- 8 sinusoidal signals to 8 channels of MUX chip in 4 K probe
- Line rate 1.56 MHz





Analog SQUID MUX power

1st stage of amplification ~ 3 nW per column

2nd stage of amplification (series-array SQUIDs)

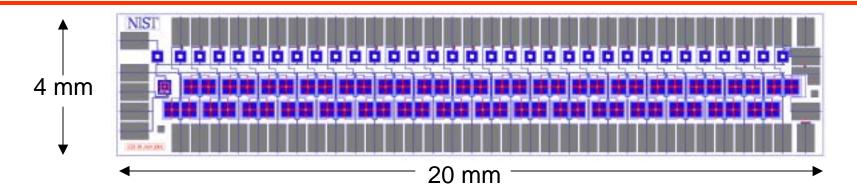
~ 300 nW per column

Total power for a 1000-pixel (32×32) array:

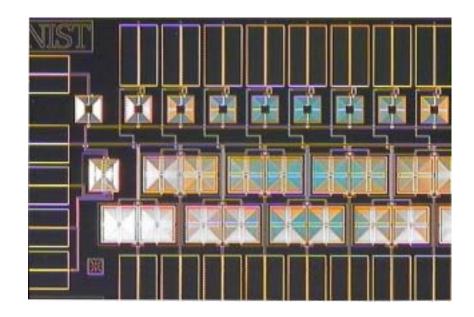
~ 100 nW 1st stage

 $\sim 10 \,\mu\text{W} \, 2^{\text{nd}} \, \text{stage}$

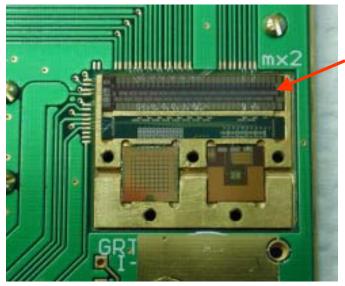
2nd-Generation 32 x N Multiplexer



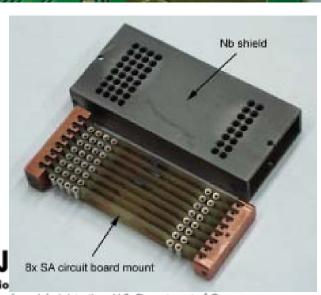
• Need 32 chips to instrument kilopixel array.

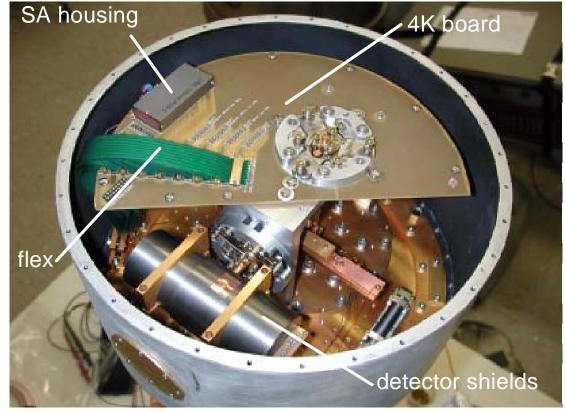


0.1 K ADR Test Facility









Technology Administration, U.S. Department of Commerce

Digital feedback electronics

Digital feedback card (one per column)

3U rack controls 16 columns



Digital FB working

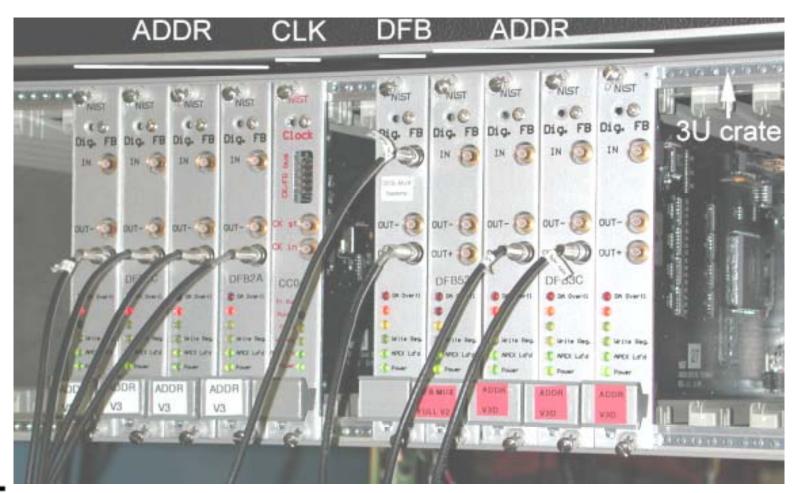
MUXing SQUIDs up to 1.6 MSa/sec

Much faster chips available

PCI Card

Computer

Room-Temperature Electronics





National Institute of Standards and Technology Technology Administration, U.S. Department of Commerce

TDM Instruments

NIST x-ray microanalysis array

1000-pixel array of TES x-ray microcalorimeters. To be used for microanalysis on an SEM.

SAFIRE

12x24 array of submillimeter bolometers in an imaging Fabry Perot. For SOFIA. Array development by NASA/GSFC IR astrophysics branch & NIST.

SCUBA-2

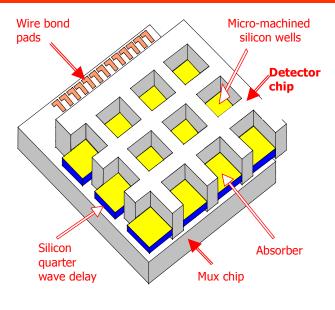
>10,000-pixel submillimeter bolometer array to be deployed at the 15 m JCMT in ~ 2006. Array development by Astronomy Technology Centre in Edinburgh and NIST.

Constellation-X (primary option; not yet downselected)

Four 1000-pixel arrays of multiplexed microcalorimeters would be flown on separate satellites. First launch scheduled for ~ 2008. Array development by NASA/GSFC x-ray calorimeter group and NIST.

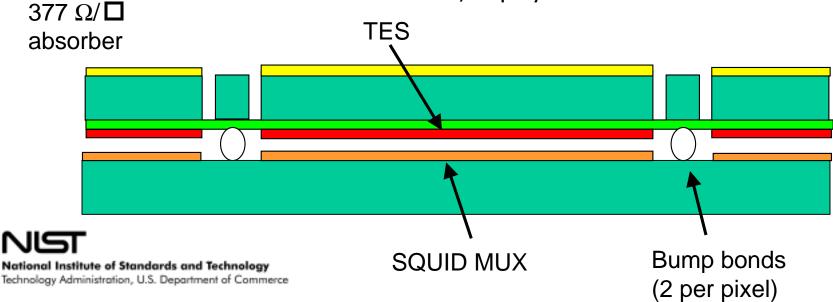


SCUBA-2: 10,240-pixel in-focal-plane MUX

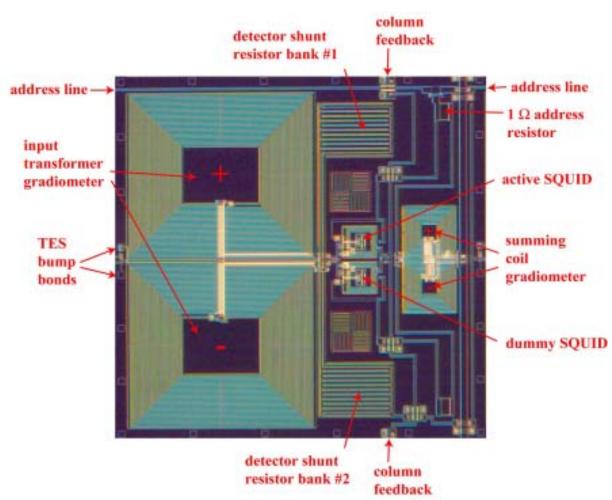


Similar to CEA Saclay architecture.

- Collaboration of the UK ATC, many institutions in the UK and Canada, NIST, and Raytheon.
- 5,120 pixels at 450 μm and 5,120 pixels at 850 μm
- First full 32×40 subarray will be tested in late 2003, deployed at JCMT in 2006



SCUBA-2 MUX Pixel



 \rightarrow The MUX will degrade the noise of the SCUBA-2 850 μm array by 1.6% (due to aliased amplifier and detector noise).

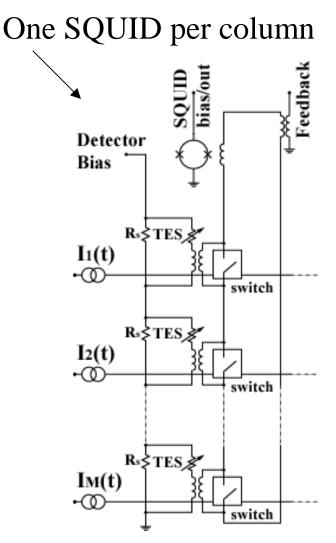
National Institute of Standards and Technology

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Alternative switches

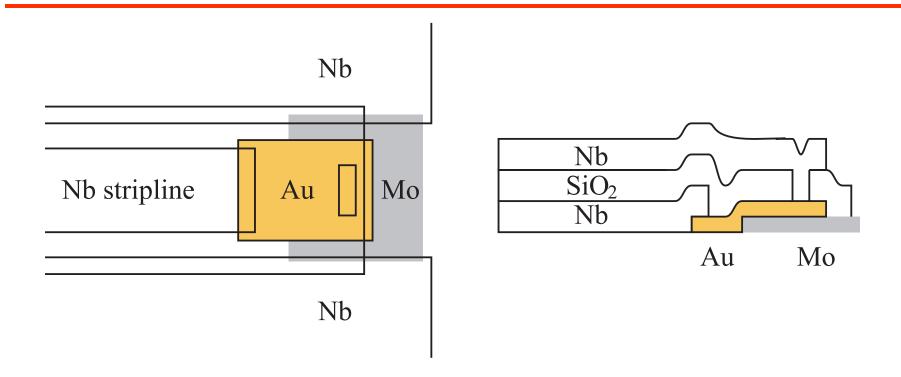
For TDM, we need highspeed, low-power, lowimpedance switches

- SQUID switches
- MEMS switches
- Flux switches
- Thermal switches





Hot-Electron Switch



When address current flows through the normalmetal, hot electrons diffuse into the superconductor, driving it normal. When the heat is turned off, they escape into the phonon system.



Hot-Electron Switch

- Simple, small, linear, and low power.
- HEBs operate at >> 1 GHz
- We estimate that with simple, high-yield optical lithography, HESs might be made with ~ 20 MHz bandwidth and < 1 nW power dissipation.

SQUID MUX above 2 K

SQUIDs work well at 4 K, should work up to some distance below the 9 K Nb transition.

Noise goes up but still more than enough margin $(0.15 \,\mu\Phi_0/\text{rt(Hz)})$ at $0.1 \,\mathrm{K} \,\mu\Phi_0/\text{rt(Hz)}$ at $4 \,\mathrm{K.})$

Hot-electron switches based on Nb instead of Mo should work up to ~ 9 K.

FDM filters based on superconducting coils work below Nb transition.

SQUID MUX above 9 K

High-T_c SQUIDs are available, but they are not simple integrated circuits.

For TDM, you need switches and fairly small filters. SQUID switches are possible *but require a high Tc SQUID for every pixel*. Other switches (MEMS switches, heat switches, flux switches) require considerable development.

For FDM, you need large filters at each pixel (L \sim 40 μ H, C \sim 1 nF) with high-Tc superconducting coils, or very high-frequency operation and slew rates.

Lots of development required

